

# 50V/12A Switching Applications

## **Applications**

· Relay drivers, high-speed inverters, converters, and other general high-current switching applications.

#### **Features**

- $\cdot$  Low-saturation collector-to-emitter voltage :  $V_{CE(sat)}\!\!=\!\!-0.5V(PNP),\,0.4V(NPN)$  max.
- · Wide ASO leading to high resistance to breakdown.

(): 2SB828

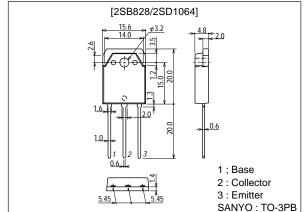
## **Specifications**

### **Absolute Maximum Ratings** at Ta = 25°C

## **Package Dimensions**

unit:mm

2022A



Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>СВО</sub>		(-)60	V
Collector-to-Emitter Voltage	VCEO		(–)50	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		(–)6	V
Collector Current	IC		(–)12	Α
Collector Current (Pulse)	ICP		(–)17	Α
Collector Dissipation	PC	Tc=25°C	80	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector Cutoff Current	ICBO	V <sub>CB</sub> =(-)40V, I <sub>E</sub> =0			(-)0.1	mA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =(-)4V, I <sub>C</sub> =0			(–)0.1	mA
DC Current Gain	h <sub>FE</sub> 1	V <sub>CE</sub> =(-)2V, I <sub>C</sub> =(-)1A	70*		280*	
	h <sub>FE</sub> 2	V <sub>CE</sub> =(-)2V, I <sub>C</sub> =(-)5A	30			
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =(-)5V, I <sub>C</sub> =(-)1A		10		MHz
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =(-)6A, I <sub>B</sub> =(-)0.3A			0.4	V
					(-0.5)	V

 $<sup>\</sup>ast$  : The 2SB828/2SD1064 are classified by 1A  $h_{FE}$  as follows :

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Rank	Q	R	S
h <sub>FE</sub>	70 to 140	100 to 200	140 to 280

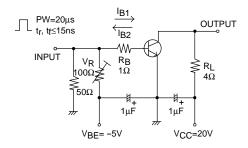
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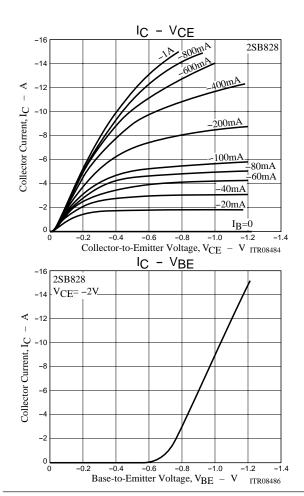
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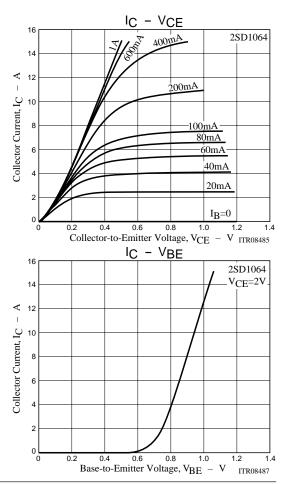
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector-to-Base Breakdown Voltage	V <sub>(BR)</sub> CBO	I <sub>C</sub> =(-)1mA, I <sub>E</sub> =0	(–)60			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I <sub>C</sub> =(-)1mA, R <sub>BE</sub> =∞	(-)50			V
Emitter-to-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =(-)1mA, I <sub>C</sub> =0	(–)6			V
Turn-ON Time	ton	See specified Test Circuit		(0.2)		μs
				0.1		μs
Fall Time	t <sub>f</sub>	See specified Test Circuit		(0.4)		μs
				1.2		μs
Storage Time	t <sub>stg</sub>	See specified Test Circuit		(0.1)		μs
				0.05		μs

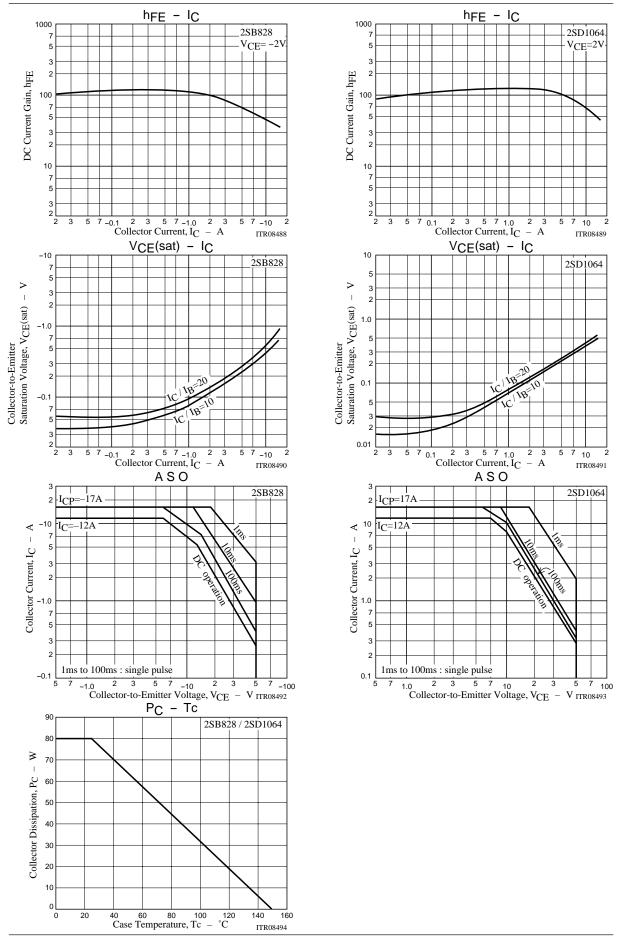
### **Switching Time Test Circuit**



 $I_{C}=10I_{B1}=-10I_{B2}=5A$  (For PNP, the polarity is reversed.)







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